Research article

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Waveguide excitation and collection of surface-enhanced Raman scattering from a single plasmonic antenna

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Abstract: The integration of plasmonic antennas on single-mode silicon nitride waveguides offers great perspective for integrated surface-enhanced Raman spectroscopy (SERS). However, the few reported experimental demonstrations still require multiple plasmonic antennas to obtain a detectable SERS spectrum. Here, we show, for the first time, SERS signal detection by a single nanoplasmonic antenna integrated on a single-mode SiN waveguide. For this purpose, we investigated a backscattering detection scheme in combination with background noise reduction, which allowed an optimization of the signal-to-noise ratio (SNR) of this platform. Furthermore, a comparison with the free-space SERS spectrum of the same antenna shows that the conversion efficiency from pump power to total radiated Stokes power is twice as efficient in the case of waveguide excitation. As such, we explored several important aspects in the optimization of on-chip SERS sensors and experimentally demonstrated the power of exciting nanoplasmonic antennas using the evanescent field of a waveguide. This observation not only is useful for Raman sensing but also could be beneficial for any process involving plasmonic enhancement.

Keywords: integrated photonics; plasmonics; surface-enhanced Raman spectroscopy.

1 Introduction

The fingerprint specificity of Raman spectroscopy could make it an ideal identification or imaging technique for a plethora of applications. However, most molecules have a very small Raman cross-section, resulting in extremely weak signals. Methods for enhancing these weak Raman signals have seen a tremendous progress over the last decades, typically based either on nonlinear Raman scattering processes, such as coherent anti-Stokes and stimulated Raman scattering [1, 2], or on a strong local field enhancement, such as surface-enhanced Raman scattering [3–15] using either metals or dielectrics [16]. More recently, alternative geometries to the conventional microscope-based setup have been developed for collecting an increased amount of Raman scattering, such as hollow-core photonic crystal fibers [17] and nanophotonic waveguides on photonic integrated circuits (PICs) [18–21]. The latter make use of the strong evanescent field on the surface of nanophotonic waveguides to efficiently excite and collect Raman scattering of molecules in the vicinity of the waveguide. Due to the long interaction length along the waveguide, waveguide-enhanced Raman can collect 10–100 times more Raman signal as compared with conventional, free-space systems [18]. A hybrid integration of plasmonic nano-antennas with dielectric nanophotonic waveguides furthermore enabled waveguide-based excitation [22, 23] and collection of SERS spectra [24–27]. This approach holds the perspective of bringing the sensitivity and selectivity of SERS measurements to a fully integrated lab-on-a-chip. Technological developments over the last
decades have led to a continuing improvement of both the sensitivity and the reproducibility of free-space SERS substrates [9, 12, 13], up to the limit of single-molecule detection on top-down fabricated nano-antennas [28]. In contrast, the sensitivity of current waveguide-based SERS systems is still far away from the single-molecule detection limit. To date, even multiple gold structures are needed to achieve a detectable SERS signal [24]. On one hand, this limited sensitivity is due to technological and conceptual challenges related to the hybrid integration of gold nano-antennas on single-mode dielectric photonic waveguides, complicating the fabrication of superior geometries with nanometer-sized gaps. On the other hand, background Stokes scattering from the waveguide material itself will be superimposed on the SERS signal, limiting the signal-to-noise ratio (SNR) through shot noise [29]. In contrast to conventional waveguide-based Raman, absorption of the plasmonic structures limits the signal gain when increasing the waveguide length.

In this manuscript, we show, for the first time, SERS signal detection from a single nanoplasmonic antenna integrated on a single-mode silicon nitride (SiN) waveguide. For this purpose, we investigated both numerically and experimentally how the length of the access waveguide and number of plasmonic antennas influence the SNR in a backscattering detection scheme. Furthermore, we quantitatively compare the Stokes power from a single antenna collected through the waveguide to a free-space excitation and collection of the same antenna using a high numerical aperture (NA) objective. We also numerically investigated the differences in total excited Stokes scattering and collection efficiency of this Stokes scattered power in both geometries. While in both cases, an approximately equal amount of SERS scattered light is collected for a given input power, we find that the conversion efficiency from pump power to total radiated Stokes power is twice as high using waveguide-based excitation. The results described in this paper take a next step towards a sensitive integrated SERS platform and provide valuable insight for the development of future waveguide-based plasmonic sensors.

2 Results

Gold bowtie antennas were patterned on single-mode silicon nitride waveguides according to a previously reported method [24]. Figure 1A shows an exemplary scanning electron microscopy image of such a bowtie-patterned waveguide. Two sets of waveguides were fabricated and characterized. The first one has an increasing number of bowties on each waveguide, with a length of 400 µm between the input facet of the chip and the bowtie section and a separation of 1 µm between consecutive bowties. A second set consists of single bowties on waveguides with a length increasing from 20 µm to 520 µm. Both sets will be described further in this manuscript. We repeatedly managed to fabricate these bowtie-patterned waveguides; however, there are a number of fabrication imperfections during the two-step electron beam lithography. The two most prominent effects can be seen from Figure 1A. First, there is a consistent misalignment of 174 ± 3 nm between the center of the waveguide and the center of the bowties due to mechanical drift in the electron beam. Furthermore, close-ups of eight randomly selected bowties...
show some heterogeneity between the different structures, having a gap $g$ of $37 \pm 9$ nm, height of $138 \pm 5$ nm, and width of $140 \pm 15$ nm. These variations have only a limited influence on both the field intensity in the gap and the spectral properties of the localized surface plasmon polariton. These effects were simulated through three-dimensional (3D) FDTD and described in more detail in the Supplementary Information (SI). In future, a reduction of the fabrication variations could be possible through an in-depth process optimization or the use of techniques to directly pattern nanostructures on topographical samples with nanometer resolution such as induced-deposition mask lithography [30]. After fabrication, the gold bowties were labeled with para-nitrothiophenol (pNTP), after which SERS spectra were excited and collected through the waveguide in an end-fire coupled reflection measurement, as depicted in Figure 1B and C, described in detail in the Methods section.

We first consider the dependence of the pNTP signal on the number of antennas ($N$) in a backscattering configuration. The antenna attenuates the power at the pump wavelength ($\lambda_p = 785$ nm) and Stokes wavelength ($\lambda_s$) with respective linear extinction coefficients $e_p$ and $e_s$. As a consequence, the first antenna will feel the highest excitation power. Moreover, the SERS signal generated by antenna $n$ ($n = 1 \ldots N$) still has to propagate back along the previous $n-1$ antennas. As a result, the overall SERS signal is expected to saturate for a sufficiently large $N$ as the first antenna will always contribute the most, while the signal from subsequent antennas will exponentially decrease. If a single antenna generates $P_S = \eta_s(\lambda_p, \lambda_s)P_{\text{pump}}$ guided Stokes power for a given guided input power $P_{\text{pump}}$, the overall backscattered SERS signal $P_{\text{tot}}^S$ for a given pump power at the input facet of a dielectric waveguide with length $L$ and propagation loss $\alpha_{wg}$ is given by (See SI):

$$\frac{P_{\text{tot}}^S}{P_{\text{pump}}} = \eta_s(\lambda_p, \lambda_s) e^{-2\alpha_{wg}L} \left( \frac{1}{e_p e_s} \right)^N \left( \frac{1}{e_p e_s} \right)$$

$$= \text{FOM}_s(N, \lambda_p, \lambda_s) e^{-2\alpha_{wg}L}$$  \hspace{1cm} (1)

Here, FOM$_s$ represents the Raman conversion efficiency of $N$ antennas, independent of the propagation loss of the waveguide. Figure 2A shows the backscattered Raman spectra for a set of waveguides with fixed length from the input facet to the first antenna with a varying number of antennas. The peaks associated to pNTP are highlighted with red (1080 cm$^{-1}$), green (1110 cm$^{-1}$), cyan (1340 cm$^{-1}$), and blue (1575 cm$^{-1}$). The characteristic SiN peak, originating from propagation of the mode through 400 $\mu$m of waveguide, is highlighted in orange (2330 cm$^{-1}$). For a single antenna ($N=1$), the overall SiN Raman background is still too high to resolve all pNTP peaks. Only the dominant 1340 cm$^{-1}$ peak is visible. By increasing the number of antennas, all pNTP peaks become visible. Figure 2B shows the (background subtracted) SERS signal strength of the 1340 cm$^{-1}$ peak as a function of $N$. The solid blue line represents a fit to the ideal model, while the shaded area represents the signal counts probability distribution due to differences in antenna conversion efficiency or extinction.

**Figure 2:** Waveguide-excited SERS signals for varying number of antennas.

(A) Backscattered Raman spectra of a waveguide covered with $N=1$, 10 and 40 antennas. The red (1080 cm$^{-1}$), green (1110 cm$^{-1}$), cyan (1340 cm$^{-1}$), and blue (1575 cm$^{-1}$) lines correspond to pNTP peaks [24], while the orange peak (2330 cm$^{-1}$) is associated to the SiN [18].

(B) Backscattered SERS signal of the 1340 cm$^{-1}$ peak as a function of $N$. The solid blue line represents a fit to the ideal model, while the shaded area represents the signal counts probability distribution due to differences in antenna conversion efficiency or extinction.
variations. This results in a variation on the signal counts. In particular, variations on the gap $g$ of the first antennas on the waveguide will effect $P_{RS}^\text{tot}$. In order to account for this spread, we apply a randomized fit procedure where a normal distribution for $\frac{1}{e^p e_s}$ and $\eta_A$ will generate a signal count distribution. For more details on this procedure, we refer to our earlier work [24]. The blue shaded area in Figure 2B covers all datapoints and is generated using normal distributions for $\eta_A = (4.55 \pm 1.20) \times 10^{-12}$. Based on numerical simulations with Lumerical FDTD Solutions (see SI), we calculated the theoretical value of $\eta_A = 1.11 \times 10^{-13}$ for the studied antenna geometry ($L = 138 \text{ nm}, g = 39 \text{ nm}, \alpha = 60^\circ$). Remarkably, the experimental $\eta_A$ value is strongly underestimated by the simulation. This could be due to a variety of reasons. One reason is that a chemical enhancement factor could also contribute to the overall Raman signal [31]. These possible “chemical” changes to the polarizability of pNTP upon gold-binding are not incorporated in our model, which is purely based on electromagnetic enhancement mechanisms. Furthermore, the thickness of the Ti adhesion layer plays an important role, as a decrease of the Ti thickness can increase the SERS intensity by one order of magnitude [32]. Despite the discrepancy in the absolute signal strength, it is clear that the experimental data correlate with the predicted trend for on-chip backscattered SERS sensing [33]. The signal of the first antenna, which is the strongest, is fully available at the input facet for the backscattered light, while in the forward scattering direction, it is attenuated by the subsequent antennas in the array. Hence, the backscattered signal will never be smaller than the forward scattered signal, such that the suggested formula for the backscattered Raman signal represents the maximum achievable electromagnetic SERS enhancement $S_{\text{max}} = \eta_A \frac{e_p e_s}{e^p e_s - 1}$ as a function of the geometrically tunable antenna parameters. As such, the experimental demonstration of backscattering detection and its fit to our model is an important step to optimize the detection limit of an on-chip SERS platform by maximizing the absolute signal strength.

Nevertheless, we see that even with this backscattering configuration, some signal peaks are still too small to be detected using a single antenna. The main reason for this is the SiN background, which can be mitigated by decreasing the propagation length along the waveguide. For that purpose, we studied the SNR as a function of waveguide length $L$ between the input facet and a single bowtie antenna patterned on the waveguide. Figure 3A shows the Raman spectra of a waveguide functionalized with $N = 1$ antenna, whereby the shortest length $L$ between the input facet and the antenna equals 50 $\mu$m. Figure 3B shows the corresponding SNR for all pNTP peaks as a function of length $L$. For $L < L^* = 175 \mu$m, all pNTP peaks are visible in the spectrum, which is evidenced by an SNR $\geq 1$. This is the first experimental demonstration of broadband on-chip SERS detection (as now all peaks are resolved) using a single nanoplasmonic antenna integrated on a
single-mode SiN waveguide. More information on the analytical prediction of the SNR as well as a comparison with spontaneous on-chip Raman scattering can be found in the SI. As can be seen from Figure 3A, the SiN background is still present for a 50-µm short access waveguide. This shows that a sensitive waveguide-based SERS system requires to limit the length over which Raman signals are collected to tens of micrometers.

Finally, we make a quantitative comparison of the conversion efficiency from pump power to collected Stokes scattered power on identical single bowtie antennas obtained through waveguide excitation and collection (waveguide coupled, WC) versus excitation and collection through a conventional microscope objective (free-space coupled, FSC). In both cases, the polarization of the pump laser was aligned parallel to the gap of a specific bowtie on top of a SiN waveguide. The excitation at the entrance facet of the objective was 0.5 mW for the WC measurement and 0.15 mW for the FSC measurement. This lower power was chosen to avoid reduction of pNTP into dimer-formation and 0.15 mW for the FSC measurement. This lower power was chosen to avoid reduction of pNTP into dimer-formation.

Figure 4: Free-space versus waveguide-excited single-antenna SERS spectra. (A) Raman spectra from five different waveguides with \( N = 1 \) antenna on top (BT1, …, BT5), but now the SERS signal from the antenna is excited and collected using a top-down configuration and not through the waveguide. (B) Comparison between the SERS signal of the 1340 cm\(^{-1} \) peak, excited and collected through the waveguide (WC) and through the objective (FSC). The signal values of the FSC measurements were re-scaled to normalize them with respect to the excitation power of the waveguide measurement.

that is \( 62 \pm 20\% \) of that using a 0.9 NA objective. While these experimental data show the overall conversion from pump power to collected Stokes power, both the excitation of the localized surface plasmon resonance and the collection of Stokes scattered light have a different efficiency in the waveguide-coupled case as compared to the FSC measurement. Therefore, it is of interest to compare the efficiency by which the total radiated Stokes power is collected by either the objective (FSC) or the waveguide (WC). The collected Stokes power \( P_{\text{WC}} \) into the fundamental backward propagating mode is given by \( P_{\text{WC}} = \beta_{\text{WC}} P_{\text{rad}} \), where \( \beta_{\text{WC}} \) is the collection efficiency into the backward propagating mode and \( P_{\text{rad}} \) is the total radiated power in the case of waveguide-coupled excitation. The conversion efficiency of pump power to Stokes scattered power \( \xi_{\text{WC}} \) is determined by \( \xi_{\text{WC}} = P_{\text{rad}} / P_{\text{pump}} \). In a similar way, we can write this down for the FSC case, \( P_{\text{FSC}} = \beta_{\text{FSC}} P_{\text{rad}} \) and \( \xi_{\text{FSC}} = P_{\text{rad}} / P_{\text{pump}} \), where the same excitation power \( P_{\text{pump}} \) as for the WC case is used. From the data in Figure 4B, we derived that for the same excitation power, the collected Stokes power \( P_{\text{WC}} = (0.62 \pm 0.2) \times P_{\text{FSC}} \), such that \( \xi_{\text{WC}} = 0.62 \frac{\beta_{\text{FSC}}}{\beta_{\text{WC}}} \xi_{\text{FSC}} \). The overall conversion efficiency from pump to Stokes power for the WC case is hence \( 0.62 \frac{\beta_{\text{FSC}}}{\beta_{\text{WC}}} \), more efficient compared to the FSC case. In order to assess \( \beta_{\text{FSC}} \) and \( \beta_{\text{WC}} \), we simulated a radiating dipole source in the center of the gap of a bowtie antenna (\( L = 133 \) nm, \( \Delta = 37 \) nm, rad and an offset of 172 nm with respect to the center of the waveguide) and calculated the mode-coupled power and the power radiated within a numerical aperture of NA = 0.9. Based on these calculations, we estimate \( \beta_{\text{FSC}} = 15.2\% \) and \( \beta_{\text{WC}} = 5.5\% \) at 1340 cm\(^{-1} \). As such, edge coupled excitation is about two times more efficient...
than top down excitation using a 0.9-NA objective, at least for this particular geometry.

3 Conclusion

In conclusion, we showed SERS signal detection by a single nanoplasmonic antenna integrated on a single-mode SiN waveguide and investigated how the performance of a single integrated antenna compares to the performance of an identical, free-space excited, antenna. We found that the overall conversion efficiency from pump power to total radiated Stokes is twice as large as compared free-space excitation with a high NA (0.9) objective; however, a lower collection efficiency implies that the total amount of collected Stokes power is comparable in both systems. In order to obtain single antenna signal detection, we implemented a backscattering detection scheme in combination with background noise reduction, which allowed an optimization of the SNR of this platform. At waveguide lengths above 50 µm, the SNR of the system is clearly limited by the SiN background signal. In the future, a further increase in sensitivity could be achieved from a further reduction of the access waveguide length to a few micrometers or an increase of the plasmonic enhancement of the nanoantennas. An important asset of an integrated antenna is that it can always be aligned by fabrication with the ideal polarization, easing optimal excitation and stability. Combined with an integrated laser source and detector, an on-chip SERS probe could hence outperform traditional SERS sensing and provide a potentially more efficient platform for Raman sensing. Our results highlight several important aspects in the optimization of on-chip SERS sensors and, moreover, experimentally show the strength of exciting nanoplasmonic antennas using the evanescent field of a waveguide as opposed to free-space excitation. The latter observation is not only useful for Raman sensing but also could be beneficial for any process involving plasmonic enhancement, such as fluorescence enhancement of two-dimensional materials [35], nonlinear optics [36], and quantum optics [37].

4 Methods

4.1 Fabrication of bowtie-patterned waveguides

The fabrication process is similar to that described in our earlier work [24]. Briefly, the device is fabricated using a two e-beam lithographic steps. In the first step, gold nanoantennas are patterned on a Si/SiO₂/SiN slab. PMMA resist (3% chlorobenzene) is used for 2 nm Ti/30 nm Au lift-off. The Ti/Au layer is deposited in a Pfeiffer Spider sputter system. In the second step, the SiN waveguides are defined. After metal lift-off, ma-N 2405 resist is spin-coated, exposed, and developed in ma-D 525. To avoid charging effects, a thin layer of e-spacer is also spun on top of the ma-N 2405. The developed samples are then etched with an ICP plasma (C₄F₈/SF₆ mixture) in a commercial Oxford Plasmalab system. The resist is stripped with mr-Rem 700. Scanning electron microscope images were acquired on a FEI Nova 600 Nanolab Dual-Beam FIB system, using a voltage of 18 kV and a through the lens (TLD) detection.

4.2 Surface functionalization

The chip was labeled with para-nitrothiophenol (pNTP, Sigma), which selectively binds through the gold surface through a gold-thiol bond and serves as a model molecule for quantifying the surface enhancement. To this end, the chips were first cleaned with aceton and IPA and dried with a nitrogen gun. Next, a short O₂ plasma (PVA-TEPLA GIGAbatch 310 m, 6000 sccm O₂, 600 W, 750 mTorr) was applied to further remove contaminants and render the gold surface hydrophilic. Subsequently, the chips were immersed in a 1-mm pNTP solution in ethanol. After overnight labeling, excess molecules were washed out by rinsing the chip extensively with ethanol and water.

4.3 SERS measurements

A commercial confocal Raman microscope (WITEC Alpha300R+) was used for coupling the light in and out of the chip, which is positioned vertically and end-fire coupled, as shown in Figure 1B and C. The same microscope was used for collecting a conventional free-space excited and collected SERS spectrum on the same bowties, which allowed for an accurate comparison between both. A 785-nm excitation diode laser (Toptica XTRA II) was used for excitation. The polarization of the excitation beam was set to be in line with the long axis of the bowties, which corresponded to the TE mode when using waveguide-based excitation. A laser power of 0.5 mW (waveguide coupled) or 0.15 mW (free space) was measured at the entrance facet of a Zeiss 100x/0.9 EC Epiplan NEOFLUAR; ∞/0 objective. The scattered signal was collected in an upright reflection mode using the same objective and imaged on a 100-m multimode fiber. This
4.4 FDTD simulation

The 3D Lumerical FDTD simulation model was described in detail in our earlier work [24]. Briefly, we considered a 700-nm-wide by 200-nm-high SiN rib waveguide with a refractive index value of 1.9 on top of an SiO2 substrate and with index 1.45. The bowties are implemented as a stack of 2-nm Ti adhesion layer in between the SiN and a 30-nm Au layer, respectively modeled using the built-in CRC and Johnson & Christy models. A gold-bound monolayer of pNTP was represented by a 1-nm-thick layer with refractive index 1.62 [38]. A mode source was used to launch the fundamental TE mode in the SiN strip waveguide, and the conversion efficiency of this mode to Stokes scattered light was calculated as described in the SI.

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References


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